	Type	Hits	Search Text	DBs	Time Stamp
1	BRS	225	ortiz.xa.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:21
2	BRS	189	Edgar$3.xa.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:21
3	BRS	89	ortiz.xa. and Edgar$3.xa.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:22
4	BRS	40	gate adj oxide and (ortiz.xa. and Edgar$3.xa.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:23
5	BRS	15	(gate adj oxide and (ortiz.xa. and Edgar$3.xa.)) and (gate adj oxide same (nitrogen or "N" or N.sub.2" or "NO" or "NO.sub.2"))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:30
6	BRS	7585	(gate adj oxide with (nitrogen or "N" or N.sub.2" or "NO" or "NO.sub.2"))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:34
7	BRS	1783	(gate adj oxide) with (nitrogen or " N.sub.2" or "NO" or "NO.sub.2")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:36
8	BRS	1296	(gate adj oxide) with ("NO" or "NO.sub.2")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:38
9	BRS	17303676	@ad<=19970827 .	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:40
10	BRS	598234	@rlad<=19970827	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:40
11	BRS	5585	(gate adj oxide with (nitrogen or "N" or N.sub.2" or "NO" or "NO.sub.2"))) and @ad<=19970827	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:44
12	BRS	1295	(gate adj oxide with (nitrogen or "N" or N.sub.2" or "NO" or "NO.sub.2"))) and @rlad<=19970827	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:43
13	BRS	5849	(((gate adj oxide with (nitrogen or "N" or N.sub.2" or "NO" or "NO.sub.2"))) and @ad<=19970827) (((gate adj oxide with (nitrogen or "N" or N.sub.2" or "NO" or "NO.sub.2")) and @rlad<=19970827)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:43
14	BRS	773	((gate adj oxide) with ("NO" or "NO.sub.2")) and @ad<=19970827	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:44
15	BRS	271	((gate adj oxide) with ("NO" or "NO.sub.2")) and @rlad<=19970827	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:44
16	BRS	835	(((gate adj oxide) with ("NO" or "NO.sub.2")) and @ad<=19970827) (((gate adj oxide) with ("NO" or "NO.sub.2")) and @rlad<=19970827)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 11:45
17	BRS	0	5990517.URPN.	USPAT	2002/02/24 11:59
18	BRS	3	("5554876" | "5773325" | "5808348").PN.	USPAT	2002/02/24 11:59
19	IS&R	2	("5990517").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/24 16:07
20	BRS	0	5990517 URPN.	USPAT	2002/02/24 16:08
21	BRS	3	("5554876" | "5773325" | "5808348").PN.	USPAT	2002/02/24 16:09

⊕ 🗁 Drafts
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🗚 Active
🗑 Failed
⊕ 📂 Saved
  🔖 (555) (ion adj implantation) with nitrogen
  🔖 (15106) gate adj oxide
  🔖 (20) ((ion adj implantation) with nitrogen) with (gate adj oxide)
  🔖 (190) (gate adj oxide)with nitrogen
  🔖 (30002) gate adj electrode
  🔖 (33) ((gate adj oxide)with nitrogen) with (gate adj electrode)
  🔖 (1915) hot adj carrier
  🔖 (190) (gate adj oxide)with nitrogen
  🔖 (52) (hot adj carrier) and ((gate adj oxide)with nitrogen)
  🔖 (1) ("5990517").PN.
  🔖 (1379) hot adj carrier
  🔖 (164) (gate adj oxide)with nitrogen
  🔖 (9) (hot adj carrier) and ((gate adj oxide)with nitrogen)
  🔖 (0) (gate adj oxide)with nitrogen
  🔖 (17) hot adj carrier
  🔖 (3) (("5554876") or ("5773325") or ("5808348")).PN.
  🔖 (0) ("nitrogen and 2").PN.
  🔖 (620) oxide and (("438/216,261,287,591,954,981").CCLS.)
  🔖 (665) ("438/216,261,287,591,954,981").CCLS.
  🔖 (226) nitrogen and (("438/216,261,287,591,954,981").CCLS.)
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U ⊨⊸ Document ID Issue Date Pages   Title   Current OR Current XRef R

🔖 Hits ⊙ Details

Saved
- (554344) ((SIDE ADJ WALL) OR SIDEWALL)
- (97645) (ANNEAL OR ANNEALING)
- (461213) nitrogen
- (3834) (((ANNEAL OR ANNEALING)) WITH (NITROGEN)))
- (98) ((((ANNEAL OR ANNEALING)) WITH (NITROGEN))) SAME (((SIDE ADJ WALL) OR SIDEWALL)))
- (77) ((((((ANNEAL OR ANNEALING)) WITH (NITROGEN))) SAME (((SIDE ADJ WALL) OR SIDEWALL)))) AND GATE)
- (62) ((((((ANNEAL OR ANNEALING)) WITH (NITROGEN))) SAME (((SIDE ADJ WALL) OR SIDEWALL)))) AND PO

Favorites
UDC

	U		Document ID	Issue Date	Pages	Title	Current OR	Current XRef
1			US 5691212 A		7	MOS device structure and integration method		
2			JP 04010547 A		5	MANUFACTURE OF SEMICONDUCTOR DEVICE		
3			JP 04139882 A		5	THIN FILM TRANSISTOR		
4			US 5554871 A	19960910	51	Semiconductor device having MOS transistor with nitrogen doping	257/336	257/344 257/408
5			US 5691212 A	19971125	7	MOS device structure and integration method	438/297	438/300 438/303
6			US 5702988 A	19971230	33	Blending integrated circuit technology	438/238	438/199 438/253
7			US 5731233 A	19980324	50	Semiconductor device having MOS transistor and method of manufacturing	438/199	438/219 438/231
8			US 5861335 A	19990119	9	Semiconductor fabrication employing a post-implant anneal within a low	438/308	438/227 438/301
9			US 5911103 A	19990608	50	Semiconductor device having MOS transistor and method of manufacturing	438/199	438/219 438/231
10			US 5937300 A	19990810	24	Semiconductor apparatus and fabrication method thereof	438/300	438/303 438/586
11			US 5960319 A	19990928	49	Fabrication method for a semiconductor device	438/664	438/649 438/651

Details